Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:
Overall Length:
Overall Diameter:
0.424 inches
Mounting Facility Quantity:
1
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
Do-4
Electrode Internally-electrically Connected To Case:
Anode Mounting Motheral
Mounting Method:
Threaded stud
Features Provided:
Hermetically sealed case
Overall Width Across Flats: 0.430 inches
Thread Size:
0.190 inches
Semiconductor Material:
Semiconductor Material: Silicon
Voltage Rating In Volts Per Characteristic: 50.0 reverse voltage, peak
Current Rating Per Characteristic:
12.00 amperes forward current, average absolute
Maximum Operating Tempurature Per Measurement Point:
175.0 degrees celsius junction
Thread Series Designator:
Unf
Terminal Type And Quantity:
1 threaded stud and 1 tab, solder lug
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0